

FEATURES

- Extremely Low Dropout
- Low Cost
- Fixed 5V Output, Trimmed to $\pm 1\%$
- 700 μ A Quiescent Current
- 3-Pin TO-92 Package
- 1mV Line Regulation
- 5mV Load Regulation
- Thermal Limit
- 4A Output Current Guaranteed

DESCRIPTION

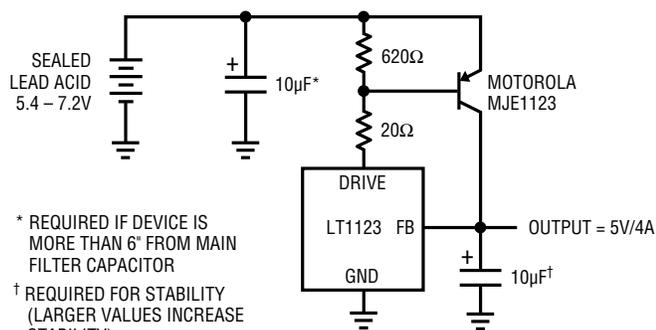
The LT1123 is a 3-pin bipolar device designed to be used in conjunction with a discrete PNP power transistor to form an inexpensive low dropout regulator. The LT1123 consists of a trimmed bandgap reference, error amplifier, and a driver circuit capable of sinking up to 125mA from the base of the external PNP pass transistor. The LT1123 is designed to provide a fixed output voltage of 5V.

The drive pin of the device can pull down to 2V at 125mA (1.4V at 10mA). This allows a resistor to be used to reduce the base drive available to the PNP and minimize the power dissipation in the LT1123. The drive current of the LT1123 is folded back as the feedback pin approaches ground to further limit the available drive current under short circuit conditions.

Total quiescent current for the LT1123 is only 700 μ A. The device is available in a low cost TO-92 package.

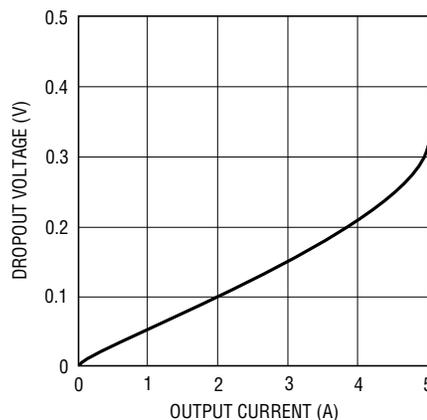
TYPICAL APPLICATION

5V Low Dropout Regulator



LT1123 TA01

Dropout Voltage



LT1123 TA02

ABSOLUTE MAXIMUM RATINGS

Drive Pin Voltage (V_{DRIVE} to Ground) 30V
 Feedback Pin Voltage (V_{FB} to Ground) 30V
 Operating Junction Temperature Range ... 0°C to 125°C
 Storage Temperature Range -65°C to 150°C
 Lead Temperature (Soldering, 10 sec.)..... 300°C

PACKAGE/ORDER INFORMATION

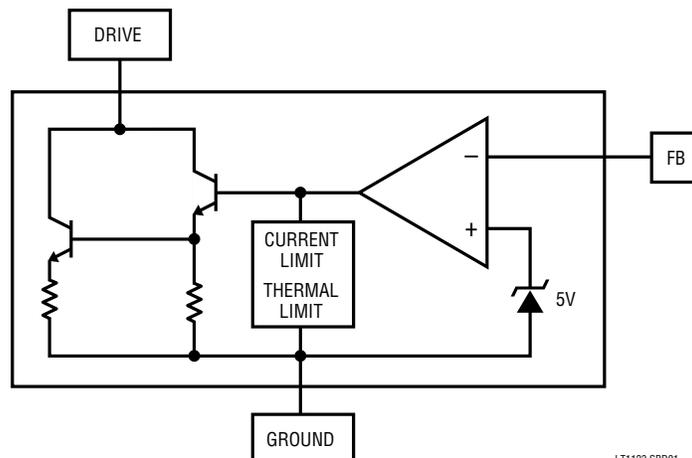
<p>3 DRIVE 2 FB 1 GND</p> <p>Z PACKAGE 3-LEAD TO-92 PLASTIC</p>	<p>ORDER PART NUMBER</p> <p>LT1123CZ</p>
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ELECTRICAL CHARACTERISTICS

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
Feedback Voltage	$I_{DRIVE} = 10mA, T_J = 25^\circ C$	4.90	5.00	5.10	V
	$5mA \leq I_{DRIVE} \leq 100mA$ $3V \leq V_{DRIVE} \leq 20V$	● 4.80	5.00	5.20	V
Feedback Pin Bias Current	$V_{FB} = 5.00V, 2V \leq V_{DRIVE} \leq 15V$	●	300	500	μA
Drive Current	$V_{FB} = 5.20V, 2V \leq V_{DRIVE} \leq 15V$	●	0.45	1.0	mA
	$V_{FB} = 4.80V, V_{DRIVE} = 3V$	●	125	170	
	$V_{FB} = 0.5V, V_{DRIVE} = 3V, \leq T_J \leq 100^\circ C$	●	25	100	
Drive Pin Saturation Voltage	$I_{DRIVE} = 10mA, V_{FB} = 4.5V$		1.4		V
	$I_{DRIVE} = 125mA, V_{FB} = 4.5V$		2.0		
Line Regulation	$5V < V_{DRIVE} < 20V$	●	1.0	± 20	mV
Load Regulation	$\Delta I_{DRIVE} = 10$ to 100mA	●	-5	-50	mV
Temperature Coefficient of V_{OUT}			0.2		$mV/^\circ C$

The ● indicates specifications which apply over the full operating temperature range.

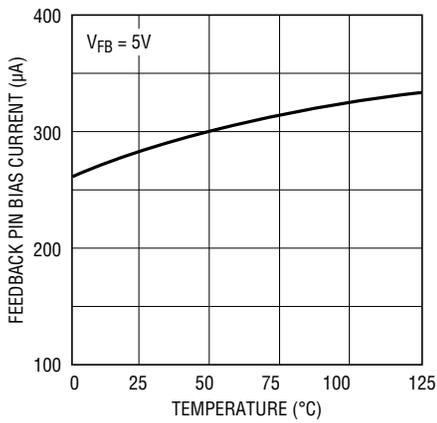
SIMPLIFIED BLOCK DIAGRAM



LT1123 S8D01

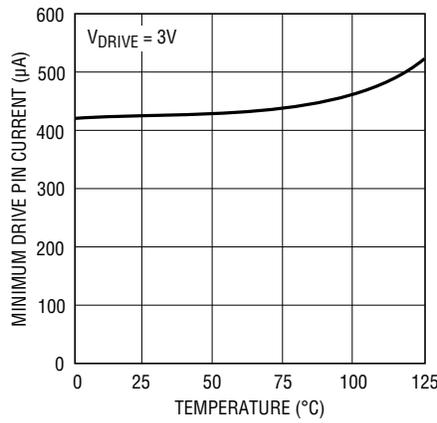
TYPICAL PERFORMANCE CHARACTERISTICS

Feedback Pin Bias Current vs Temperature



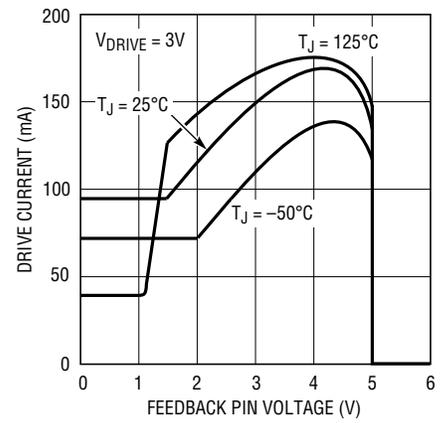
LT1123 G01

Minimum Drive Pin Current vs Temperature



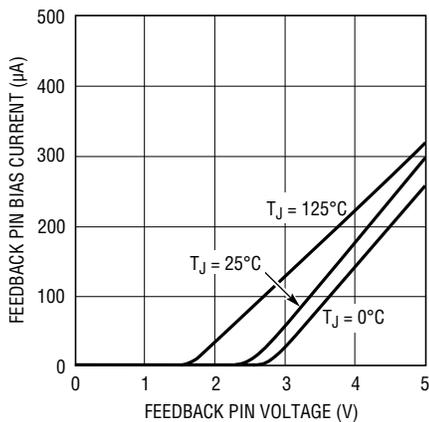
LT1123 G02

Drive Current vs Feedback Pin Voltage



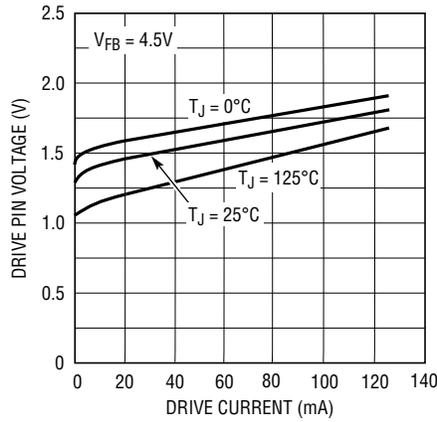
LT1123 G03

Feedback Pin Bias Current vs Feedback Pin Voltage



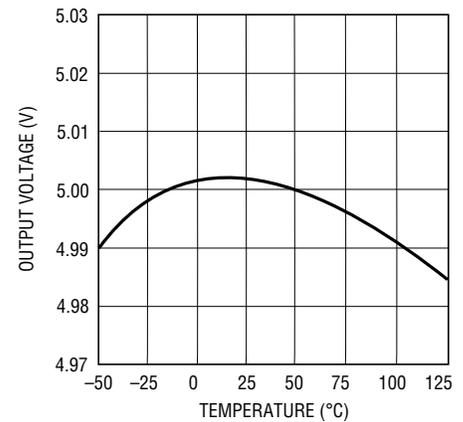
LT1123 G04

Drive Pin Saturation Voltage vs Drive Current



LT1123 G05

Output Voltage vs Temperature



LT1123 G06

FUNCTIONAL DESCRIPTION

The LT1123 is a three pin device designed to be used in conjunction with a discrete PNP transistor to form an inexpensive ultra-low dropout regulator. The device incorporates a trimmed 5V bandgap reference, error amplifier, a current-limited Darlington driver, and an internal thermal limit circuit. The internal circuitry connected to the drive pin is designed to function at the saturation voltage of the Darlington driver. This allows a resistor to be

inserted in series with the drive pin. This resistor is used to limit the base drive to the PNP and also to limit the power dissipation in the LT1123. The value of this resistor will be defined by the operating requirements of the regulator circuit. The LT1123 is designed to sink a minimum of 125mA of base current. This is sufficient base drive to form a regulator circuit which can supply output currents up to 4A at a dropout voltage of less than 0.75V.

PIN FUNCTIONS

Drive Pin: The drive pin serves two functions. It provides current to the LT1123 for its internal circuitry including startup, bias, current limit, thermal limit and a portion of the base drive current for the output Darlington. The sum total of these currents (450 μ A typical) is equal to the minimum drive current. This current is listed in the specifications as Drive Current with $V_{FB} = 5.2V$. This is the minimum current required by the drive pin of the LT1123.

The second function of the drive pin is to sink the base drive current of the external PNP pass transistor. The available drive current is specified for two conditions. Drive current with $V_{FB} = 4.80V$ gives the range of current available under nominal operating conditions, when the device is regulating. Drive current with $V_{FB} = 0.5V$ gives the range of drive current available with the feedback pin pulled low as it would be during startup or during a short circuit fault. The drive current available when the feedback pin is pulled low is less than the drive current available when the device is regulating ($V_{FB} = 5V$). This can be seen in the curve of Drive Current vs V_{FB} Voltage in the Typical Performance Characteristic curves. This can provide some foldback in the current limit of the regulator circuit.

All internal circuitry connected to the drive pin is designed to operate at the saturation voltage of the Darlington output driver (1.4 – 2V). This allows a resistor to be inserted between the base of the external PNP device and the drive pin. This resistor is used to limit the base drive to the external PNP below the value set internally by the LT1123, and also to help limit power dissipation in the LT1123. The operating voltage range of this pin is from 0V to 30V. Pulling this pin below ground by more than one V_{BE} will forward bias the substrate diode of the device. This condition can only occur if the power supply leads are reversed and will not damage the device if the current is limited to less than 200mA.

Feedback Pin (V_{FB}): The feedback pin also serves two functions. It provides a path for the bias current of the reference and error amplifier and contributes a portion of the drive current for the Darlington output driver. The sum total of these currents is the Feedback Pin Bias Current (300 μ A typical). The second function of this pin is to provide the voltage feedback to the error amplifier.

APPLICATIONS INFORMATION

The LT1123 is designed to be used in conjunction with an external PNP transistor. The overall specifications of a regulator circuit using the LT1123 and an external PNP will be heavily dependent on the specifications of the external PNP. While there are a wide variety of PNP transistors available that can be used with the LT1123, the specifications given in typical transistor data sheets are of little use in determining overall circuit performance.

Linear Technology has solved this problem by cooperating with Motorola to design and specify the MJE1123. This transistor is specifically designed to work with the LT1123 as the pass element in a low dropout regulator. The specifications of the MJE1123 reflect the capability of the LT1123. For example, the dropout voltage of the MJE1123 is specified up to 4A collector current with base drive currents that the LT1123 is capable of generating (20mA

to 120mA). Output currents up to 4A with dropout voltages less than 0.75V can be guaranteed.

The following sections describe how specifications can be determined for the basic regulator. The charts and graphs are based on the combined characteristics of the LT1123 and the MJE1123. Formulas are included that will enable the user to substitute other transistors that have been characterized. A chart is supplied that lists suggested resistor values for the most popular range of input voltages and output current.

BASIC REGULATOR CIRCUIT

The basic regulator circuit is shown in Figure 1. The LT1123 senses the voltage at its feedback pin and drives the base of the PNP (MJE1123) in order to maintain the

APPLICATIONS INFORMATION

output at 5V. The drive pin of the LT1123 can only sink current; R_B is required to provide pullup on the base of the PNP. R_B must be sized so that the voltage drop caused by the minimum drive pin current is less than the emitter/base voltage of the external PNP at light loads. The recommended value for R_B is 620Ω . For circuits that are required to run at junction temperatures in excess of 100°C the recommended value of R_B is 300Ω .

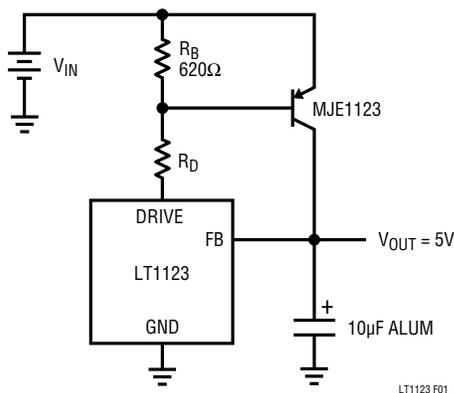


Figure 1. Basic Regulator Circuit

R_D is used to limit the drive current available to the PNP and to limit the power dissipation in the LT1123. Limiting the drive current to the PNP will limit the output current of the regulator which will minimize the stress on the regulator circuit under overload conditions. R_D is chosen based on the operating requirements of the circuit, primarily dropout voltage and output current.

DROPOUT VOLTAGE

The dropout voltage of an LT1123 based regulator circuit is determined by the V_{CE} saturation voltage of the discrete PNP when it is driven with a base current equal to the available drive current of the LT1123. The LT1123 can sink up to 150mA of base current (150mA typ., 125mA min.) when output voltage is up near the regulating point (5V). The available drive current of the LT1123 can be reduced by adding a resistor (R_D) in series with the drive pin (see the section below on current limit). The MJE1123 is specified for dropout voltage (V_{CE} sat.) at several values of output current and up to 120mA of base drive current. The chart below lists the operating points that can be guaran-

Dropout Voltage

DRIVE CURRENT	OUTPUT CURRENT	DROPOUT VOLTAGE	
		TYP	MAX
20mA	1A	0.16V	0.3V
	50mA	0.13V	0.25V
120mA	2A	0.25V	0.4V
	1A	0.2V	0.35V
	4A	0.45V	0.75V

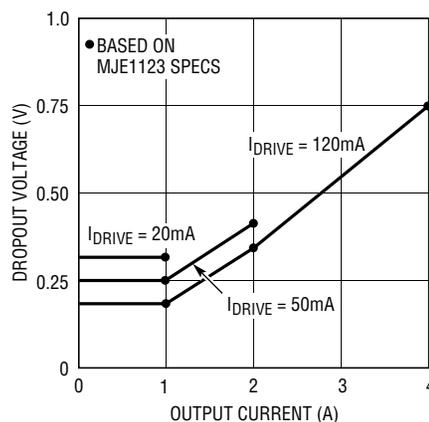


Figure 2. Maximum Dropout Voltage

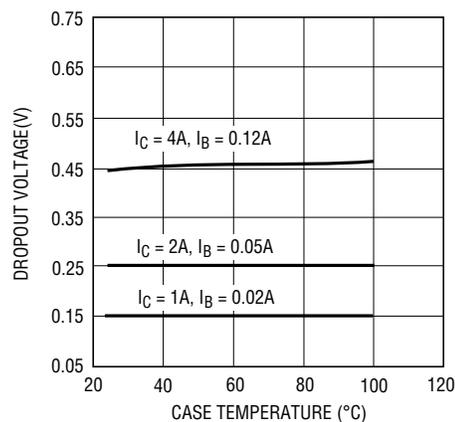


Figure 3. Dropout Voltage vs Temperature

teed by the combined data sheets of the LT1123 and MJE1123. Figure 2 illustrates the chart in graphic form. Although these numbers are only guaranteed by the data sheet at 25°C , Dropout Voltage vs Temperature (Figure 3) clearly shows that the dropout voltage is nearly constant over a wide temperature range.

APPLICATIONS INFORMATION

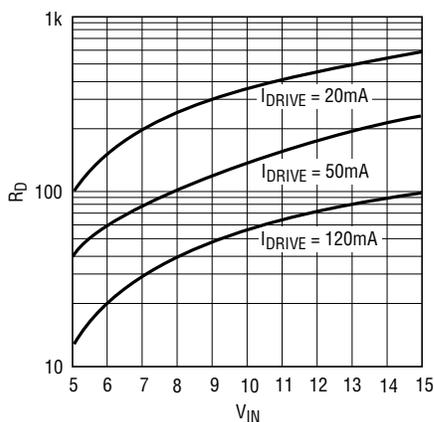
SELECTING R_D

In order to select R_D the user should first choose the value of drive current that will give the required value of output current. For circuits using the MJE1123 as a pass transistor this can be done using the graph of Dropout Voltage vs Output Current (Figure 2). For example, 20mA of drive current will guarantee a dropout voltage of 0.3V at 1A of output current. For circuits using transistors other than the MJE1123 the user must characterize the transistor to determine the drive current requirements. In general it is recommended that the user choose the lowest value of drive current that will satisfy the output current requirements. This will minimize the stress on circuit components during overload conditions.

Figure 4 can be used to select the value of R_D based on the required drive current and the minimum input voltage. Curves are shown for 20mA, 50mA, and 120mA drive current corresponding to the specified base drive currents for the MJE1123. The data for the curves was generated using the following formula:

$$R_D = (V_{IN} - V_{BE} - V_{DRIVE}) / (I_{DRIVE} + 1mA)$$

where V_{IN} = the minimum input voltage to the circuit
 V_{BE} = the maximum emitter/base voltage of the PNP pass transistor
 V_{DRIVE} = the maximum Drive pin voltage of the LT1123
 I_{DRIVE} = the minimum drive current required
 The current through R_B is assumed to be 1mA



LT1123 F04

Figure 4. R_D Resistor Value

The following assumptions were made in calculating the data for the curves. Resistors are 5% tolerance and the values shown on the curve are nominal.

For 20mA drive current assume:

$$V_{BE} = 0.95V \text{ at } I_C = 1A$$

$$V_{DRIVE} = 1.75V$$

For 50mA drive current assume:

$$V_{BE} = 1.2V \text{ at } I_C = 2A$$

$$V_{DRIVE} = 1.9V$$

For 120mA drive current assume:

$$V_{BE} = 1.4V \text{ at } I_C = 4A$$

$$V_{DRIVE} = 2.1V$$

The R_D Selection Chart lists the recommended values for R_D for the most useful range of input voltage and output current. The chart includes a number for power dissipation for the LT1123 and R_D.

R_D Selection Chart

INPUT VOLTAGE	OUTPUT CURRENT: DROPOUT VOLTAGE:	0 – 1A 0.3V	0 – 2A 0.4V	0 – 4A 0.75V
5.5V	R _D	120Ω	43Ω	—
	Power (LT1123)	0.05W	0.14W	—
	Power (R _D)	0.12W	0.32W	—
6.0V	R _D	150Ω	51Ω	20Ω
	Power (LT1123)	0.05W	0.15W	0.37W
	Power (R _D)	0.13W	0.35W	0.76W
7.0V	R _D	180Ω	75Ω	27Ω
	Power (LT1123)	0.06W	0.14W	0.38W
	Power (R _D)	0.16W	0.36W	0.89W
8.0V	R _D	240Ω	91Ω	36Ω
	Power (LT1123)	0.06W	0.15W	0.38W
	Power (R _D)	0.17W	0.42W	0.97W
9.0V	R _D	270Ω	110Ω	43Ω
	Power (LT1123)	0.20W	0.16W	0.41W
	Power (R _D)	0.07W	0.47W	1.11W
10.0V	R _D	330Ω	130Ω	51Ω
	Power (LT1123)	0.22W	0.17W	0.43W
	Power (R _D)	0.07W	0.52W	1.25W

Note that in some conditions R_D may be replaced with a short. This is possible in circuits where an overload is unlikely and the input voltage and drive requirements are low. See the section on Thermal Considerations for more information.

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CURRENT LIMIT

For regulator circuits using the LT1123, current limiting is achieved by limiting the base drive to the external PNP pass transistor. This means that the actual system current limit will be a function of both the current limit of the LT1123 and the Beta of the external PNP. Beta-based current limit schemes are normally not practical because of uncertainties in the Beta of the pass transistor. Here the drive characteristics of the LT1123 combined with the Beta characteristics of the MJE1123 can provide reliable Beta-based current limiting. This is shown in Figure 5 where the current limit of 30 randomly selected transistors is plotted. The spread of current limit is reasonably well controlled.

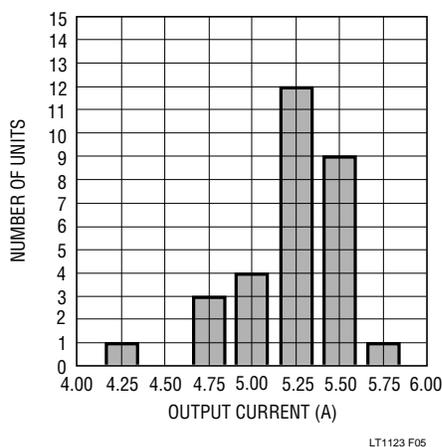


Figure 5. Short Circuit Current for 30 Random Devices

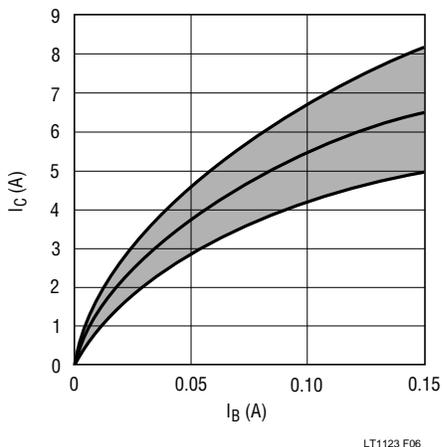


Figure 6. MJE1123 I_C vs I_B

The curve in Figure 6 can be used to determine the range of current limit of an LT1123 regulator circuit using an MJE1123 as a pass transistor. The curve was generated using the Beta versus I_C curve of the MJE1123. The minimum and maximum value curves are extrapolated from the minimum and maximum Beta specifications.

THERMAL CONSIDERATIONS

The thermal characteristics of three components need to be considered; the LT1123, the pass transistor, and R_D . Power dissipation should be calculated based on the worst case conditions seen by each component during normal operation.

The worst case power dissipation in the LT1123 is a function of drive current, supply voltage, and the value of R_D . Worst case dissipation for the LT1123 occurs when the drive current is equal to approximately one half of its maximum value. Figure 7 plots the worst case power dissipation in the LT1123 versus R_D and V_{IN} . The graph was generated using the following formula:

$$P_D = \frac{(V_{IN} - V_{BE})^2}{4R_D}; R_D > 10\Omega$$

where V_{BE} = the emitter/base voltage of the PNP pass transistor (assumed to be 0.6V)

For some operating conditions R_D may be replaced with a short. This is possible in applications where the operating

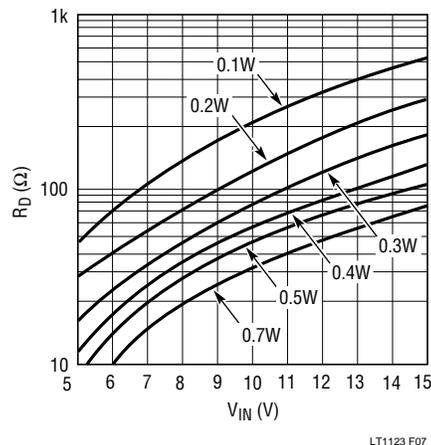


Figure 7. Power in LT1123

APPLICATIONS INFORMATION

requirements (input voltage and drive current) are at the low end and the output will not be shorted. For $R_D = 0$ the following formula may be used to calculate the maximum power dissipation in the LT1123.

$$P_D = (V_{IN} - V_{BE})(I_{DRIVE})$$

where V_{IN} = maximum input voltage
 V_{BE} = emitter/base voltage of PNP
 I_{DRIVE} = required maximum drive current

The maximum junction temperature rise above ambient for the LT1123 will be equal to the worst case power dissipation multiplied by the thermal resistance of the device. The thermal resistance of the device will depend upon how the device is mounted, and whether a heat sink is used. Measurements show that one of the most effective ways of heat sinking the TO-92 package is by utilizing the PC board traces attached to the leads of the package. The table below lists several methods of mounting and the measured value of thermal resistance for each method. All measurements were done in still air.

	THERMAL RESISTANCE
Package alone	220°C/W
Package soldered into PC board with plated through holes only	175°C/W
Package soldered into PC board with 1/4 sq. in. of copper trace per lead	145°C/W
Package soldered into PC board with plated through holes in board, no extra copper trace, and a clip-on type heat sink:	
Thermalloy type 2224B	160°C/W
Aavid type 5754	135°C/W

The maximum operating junction temperature of the LT1123 is 125°C. The maximum operating ambient temperature will be equal to 125°C minus the maximum junction temperature rise above ambient.

The worst case power dissipation in R_D needs to be calculated so that the power rating of the resistor can be determined. The worst case power in the resistor will occur when the drive current is at a maximum. Figure 8 plots the required power rating of R_D versus supply voltage and resistor value. Power dissipation can be calculated using the following formula:

$$P_{R_D} = \frac{(V_{IN} - V_{BE} - V_{DRIVE})^2}{R}$$

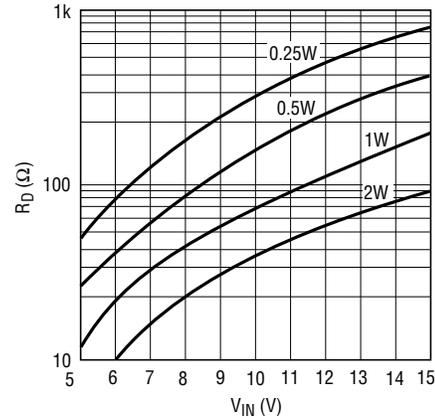


Figure 8. Power in R_D

where V_{BE} = emitter/base voltage of the PNP pass transistor
 V_{DRIVE} = voltage at the drive pin of the LT1123
 = V_{SAT} of the drive pin in the worst case

The worst case power dissipation in the PNP pass transistor is simply equal to:

$$P_{MAX} = (V_{IN} - V_{OUT})(I_{OUT})$$

where V_{IN} = Maximum V_{IN}
 I_{OUT} = Maximum I_{OUT}

The thermal resistance of the MJE1123 is equal to:
 70°C/W Junction to Ambient (no heat sink)
 1.67°C/W Junction to Case

The PNP will normally be attached to either a chassis or a heat sink so the actual thermal resistance from junction to ambient will be the sum of the PNP's junction to case thermal resistance and the thermal resistance of the heat sink or chassis. For non-standard heat sinks the user will need to determine the thermal resistance by experiment.

The maximum junction temperature rise above ambient for the PNP pass transistor will be equal to the maximum power dissipation times the thermal resistance, junction to ambient, of the PNP. The maximum operating junction temperature of the MJE1123 is 150°C. The maximum operating ambient temperature for the MJE1123 will be equal to 150°C minus the maximum junction temperature rise.

APPLICATIONS INFORMATION

THERMAL LIMITING

The thermal limit of the LT1123 can be used to protect both the LT1123 and the PNP pass transistor. This is accomplished by thermally coupling the LT1123 to the power transistor. There are clip type heat sinks available for the TO-92 package that will allow the LT1123 to be mounted to the same heat sink as the PNP pass transistor. One example is manufactured by IERC (part #RUR67B1CB). The LT1123 should be mounted as close as possible to the PNP. If the output of the regulator circuit can be shorted, heat sinking must be adequate to limit the rate of temperature rise of the power device to approximately 50°C/minute. This can be accomplished with a fairly small heat sink, on the order of 3 – 4 square inches of surface area.

DESIGN EXAMPLE

Given the following operating requirements:

$$5.5V < V_{IN} < 7V$$

$$I_{OUTMAX} = 1.5A$$

$$\text{Max ambient temp.} = 70^{\circ}C$$

$$V_{OUT} = 5V$$

1. The first step is to determine the required drive current. This can be found from the Maximum Dropout Voltage curve. 50mA of drive current will guarantee 0.4V dropout at an output current of 2A. This satisfies our requirements.

$$I_{DRIVE} = 50mA$$

2. The next step is to determine the value of R_D . Based on 50mA of drive current and a minimum input voltage of 5.5V, we can select R_D from the graph of Figure 4. From the graph the value of R_D is equal to 50Ω, so we should use the next lowest 5% value which is 47Ω.

$$R_D = 47\Omega$$

3. We can now look at the thermal requirements of the circuit.

Worst case power in the LT1123 will be equal to:

$$\frac{(V_{INMAX} - V_{BE})^2}{4R_D}$$

$$\text{Given: } V_{INMAX} = 7V, V_{BE} = 0.6V, R_D = 47\Omega$$

$$\text{Then: } P_{MAX} (LT1123) = 0.22W.$$

Assuming a thermal resistance of 150°C/W, the maximum junction temperature rise above ambient will be equal to $(P_{MAX})(150^{\circ}C/W) = 33^{\circ}C$. The maximum operating junction temperature will be equal to the maximum ambient temperature plus the junction temperature rise above ambient. In this case we have (maximum ambient = 70°C) plus (junction temperature rise = 33°C) is equal to 103°C. This is well below the maximum operating junction temperature of 125°C for the LT1123.

The power rating for R_D can be found from the plot of Figure 8 using $V_{IN} = 7V$ and $R_D = 47\Omega$. From the plot, R_D should be sized to dissipate a minimum of 1/2W.

The worst case power dissipation, for normal operation, in the MJE1123 will be equal to:

$$(V_{INMAX} - V_{OUT})(I_{OUTMAX}) = (7V - 5V)(1.5A) = 3W$$

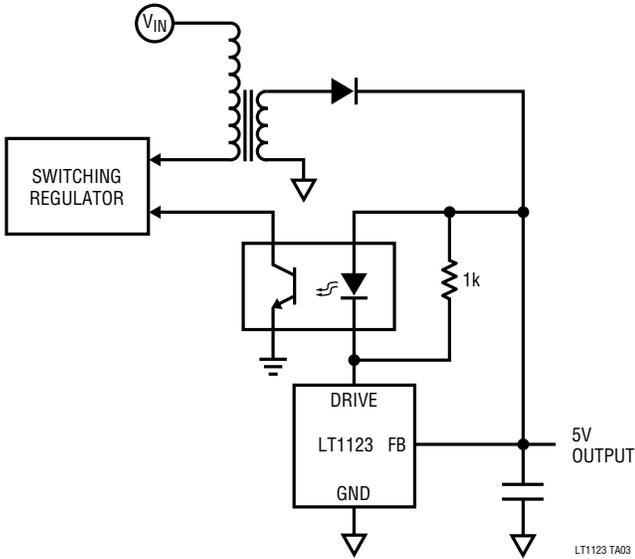
The maximum operating junction temperature of the MJE1123 is 150°C. The difference between the maximum operating junction temperature of 150°C and the maximum ambient temperature of 70°C is 80°C. The device must be mounted to a heat sink which is sized such that the thermal resistance from the junction of the MJE1123 to ambient is less than $80^{\circ}C/3W = 26.7^{\circ}C/W$.

It is recommended that the LT1123 be thermally coupled to the MJE1123 so that the thermal limit circuit of the LT1123 can protect both devices. In this case the ambient temperature for the LT1123 will be equal to the temperature of the heat sink. The heat sink temperature, under normal operating conditions, will have to be limited such that the maximum operating junction temperature of the LT1123 is not exceeded.

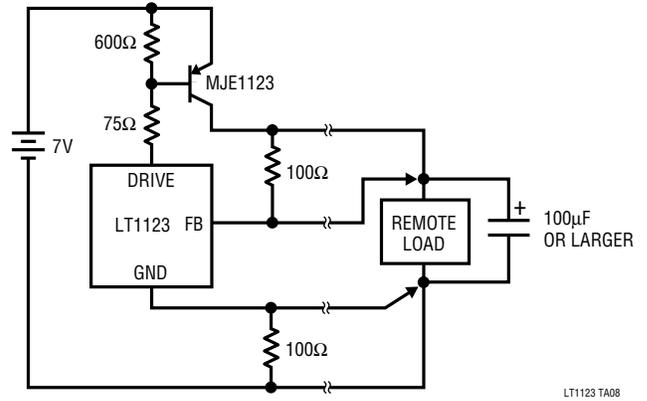
Refer to Linear Technology's list of Suggested Manufacturers of Specialized Components for information on where to find the required heat sinks, resistors and capacitors. This listing is available through Linear Technology's marketing department.

TYPICAL APPLICATIONS

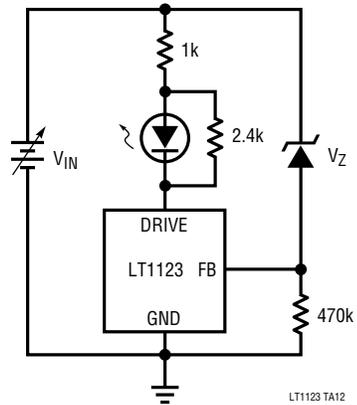
Isolated Feedback for Switching Regulators



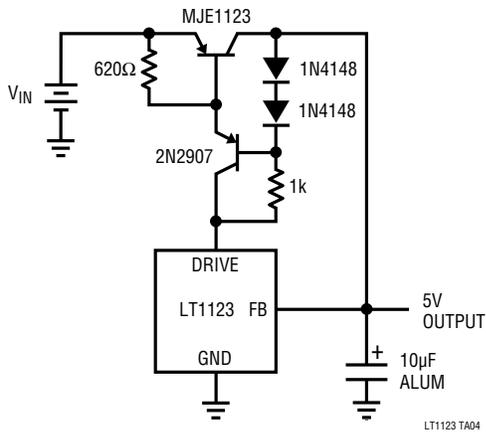
5V/2A Regulator with Remote Sensing



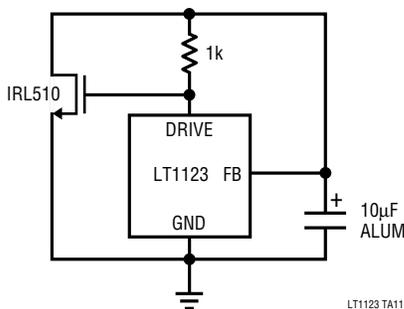
Undervoltage Indicator On for $V_{IN} < (V_Z + 5V)$



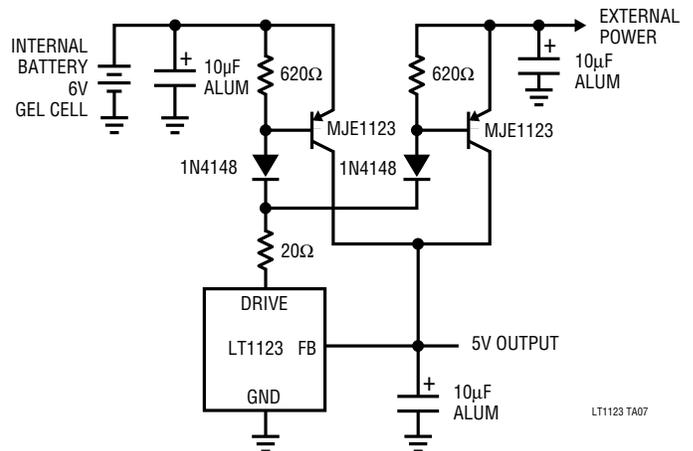
5V Regulator with Anti-Sat Miminizes Ground Pin Current in Dropout



5V Shunt Regulator or Voltage Clamp

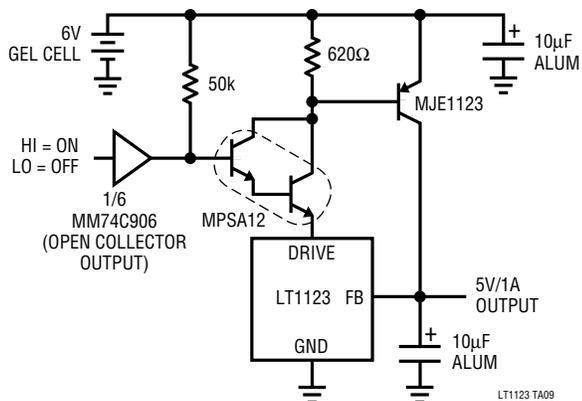


Battery Backup Regulator

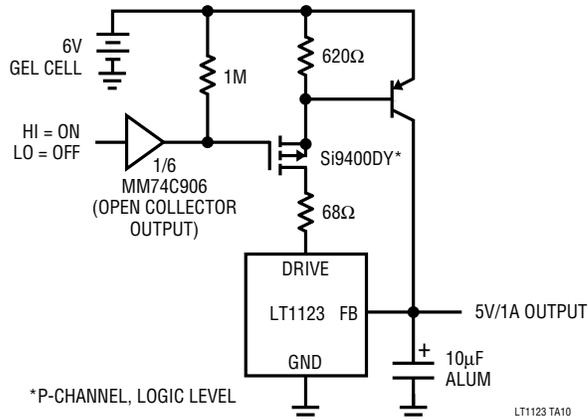


TYPICAL APPLICATIONS

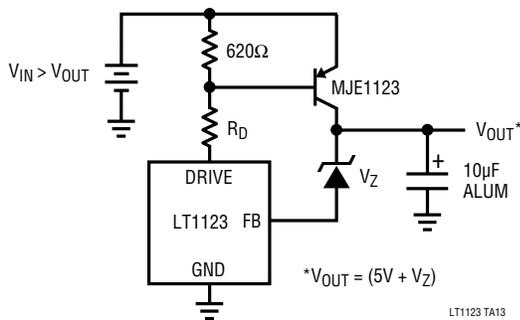
5V/1A Regulator with Shutdown



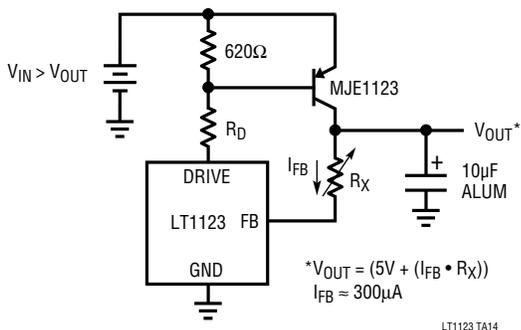
5V/1A Regulator with Shutdown



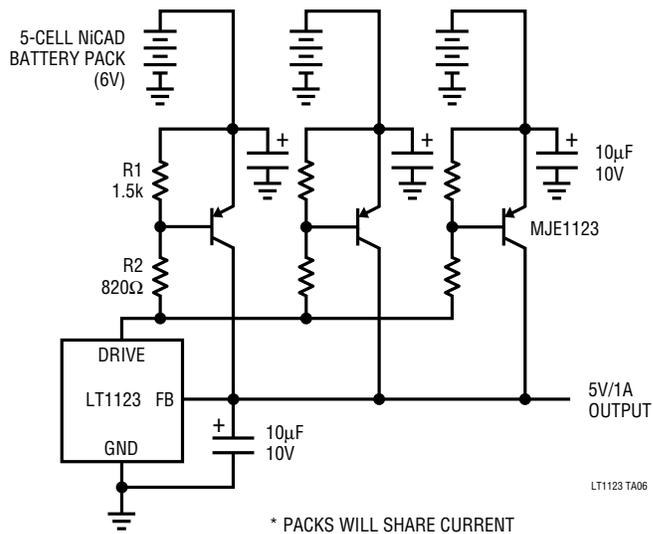
Adjusting V_{OUT}



Adjusting V_{OUT}

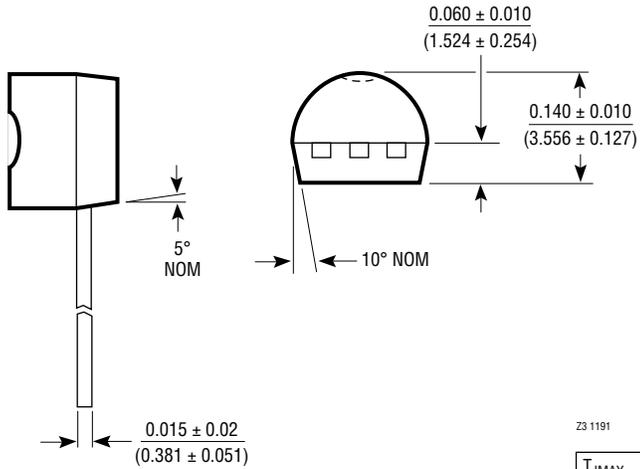
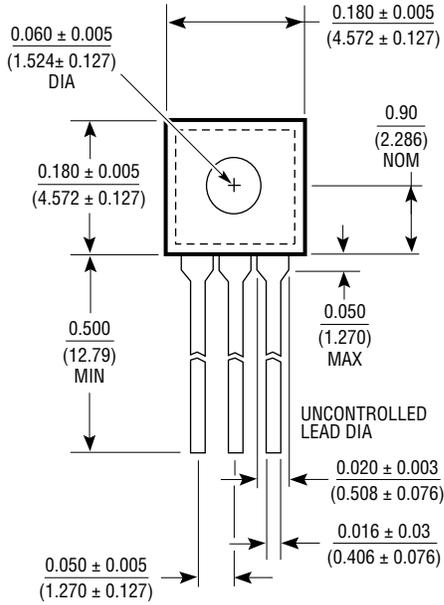


5V Regulator Powered by Multiple Battery Packs*



PACKAGE DESCRIPTION Dimensions in inches (millimeters) unless otherwise noted.

**Z Package
3-Lead TO-92**



Z3 1191

T _{JMAX}	θ _{JA}
125°C	220°C/W

SEE DATA IN THERMAL
CONSIDERATIONS